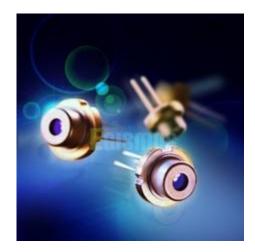
450nm Laser Diode

Egismos

Blue Laser Diode

Application Laser projection / Biomedical / Stage Lighting Property Wavelength $\lambda = 450$ nm Output Power = 80mW Package Type = φ 3.8mm Introduction

Egismos currently markets GaN based blue laser diodes 405nm, 450nm wavelengths range. The low operating current and high temperature of the laser diodes are achieved through using misoriented substrate and MQW (Strain compensated) active layer. Egismos laser diodes are highly rated in a broad range of applications including, but not limited to, laser pointers, green lasers, blue laser DVD, laser barcode scanners, diode laser equipments, medical instruments and aerospace applications.



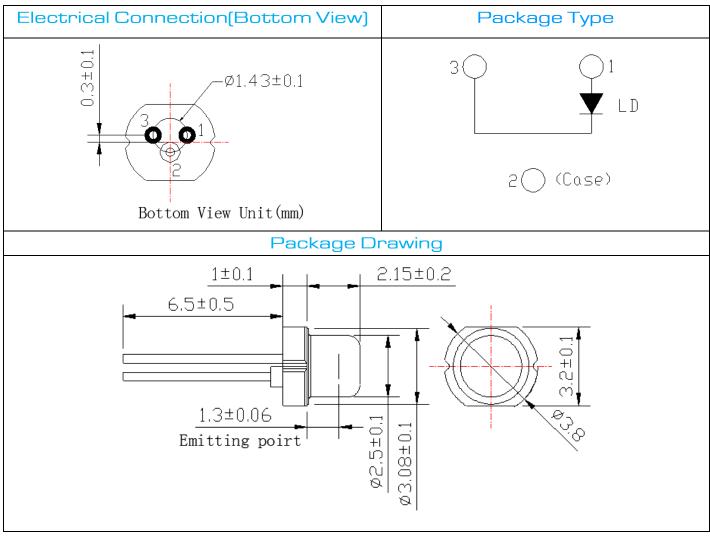
Blue Laser Diode Key features

| Absolute Maximum Rating at Tc=25 \degree | | | | | | | |
|--|---------------------|---------|------|--|--|--|--|
| Items | Symbols | Values | Unit | | | | |
| Optical Output Power | P _o (CW) | 80 | mW | | | | |
| Reverse Voltage | V _R | 2 | V | | | | |
| Operating Temperature _(case) | To | -40~+50 | °C | | | | |
| Storage Temperature | Ts | -40~+85 | °C | | | | |

| Electrical and Optical Characteristics at Tc=25 \degree | | | | | | | |
|---|-----------------|------|------|------|------|-----------|--|
| ltem | Symbols | Min | Тур. | Max. | Unit | Condition | |
| Threshold Current | I _{th} | - | 35 | 55 | mA | - | |
| Operating Current | I _{OP} | - | - | 165 | mA | Po=80mW | |
| Operating Voltage | V _{OP} | - | 5.8 | 7.0 | V | Po=80mW | |
| Peak Wavelength | λ _P | 440 | 450 | 460 | nm | Po=80mW | |
| Polarisation | P _{gr} | 20:1 | - | - | | Po=80mW | |

EGISMOS www.egismos.com tel:+1-360-3893347 sales@egismos.com EGISMOS

| | 450nm Laser Diode | | | <u>D4-5-450-80X</u> | | |
|-----------------|-------------------|----|---|---------------------|-----|---------|
| Beam Divergence | θ// | 4 | - | 11 | deg | Po=80mW |
| (FWHM) | θ⊥⊥ | 18 | - | 25 | deg | Po=80mW |



Specifications are subject to change without notice.



